**FORM PTO-1449** 

## U.S. DEPARTMENT OF COMMERCE TENT AND TRADEMARK OFFICE

PKHF-05004U 10/589,852

## LIST OF REFERENCES CITED BY APPLICANT

(Use several sheets if necessary)

Noboru ICHINOSE

FILING DATE GROUP ART UNIT

2829

November 27, 2006

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	DOCUMENT NO.	DATE	NAME	CLAS	SUB- CLAS	•	FILING DATE	
AA	6,030,453	02/29/2000	PASSLACK, et al.			1		
AB	2004/0007708	01/15/2004	ICHINOSE, et al. (Previously Submitted)					
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AG	10-289906	10/27/1998	JAPAN (See U.S. 6,030,453)					ABS
АН	10-338522	12/22/1998	JAPAN					ABS
Al	WO 02/12598	02/14/2002	WIPO					
AJ	2002-093243	03/29/2002	JAPAN (Previously Submitted)					
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	OTHER REFE	RENCES (Including	z Author, Title, Date, Pertinent Pc	iges, Etc.)		<u> </u>	<u> </u>	
L .	Japanese Office Action	n dated <b>December</b> 2, <del>200</del>	<b>প্রত</b> 9 with English Tranlsation					
М	Harwig et al., "Electrical Properties of b-Ga2O3 Single Crystals. II," Journal of Solid State Chemistry Vol. 23, pages 205-211, 15 January 1978. (Previously Submitted)							
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P 1	Tomm, Y. et al., "Floating Zone Growth of B-Ga2O3: A New Window Material for Optoelectronic Device Applications", In: Solar Energy Materials & Solar Cells, February, 2001, Vol. 66, Pages 369 to 374 (Previously Submitted)							
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EXAMINER:

Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.